

IS201, IS202, IS203, IS204,
ISD201, ISD202, ISD203, ISD204,
ISQ201, ISQ202, ISQ203, ISQ204



ISOCOM

COMPONENTS

HIGH DENSITY PHOTOTRANSISTOR OPTICALLY COUPLED ISOLATORS



APPROVALS

- UL recognised, File No. E91231
Package Code " GG " or " FF "

'X' SPECIFICATION APPROVALS

- VDE 0884 in 3 available lead form : -
 - STD
 - G form
 - SMD approved to CECC 00802
- IS20* Certified to EN60950 by : -
Nemko - Certificate No. P01102464

DESCRIPTION

The IS20*, ISD20*, ISQ20* series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photo transistors in space efficient dual in line plastic packages.

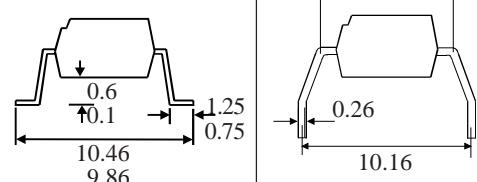
FEATURES

- Options : -
 - 10mm lead spread - add G after part no.
 - Surface mount - add SM after part no.
 - Tape&reel - add SMT&R after part no.
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- High BV_{CEO} (70V min)
- All electrical parameter 100% tested
- Custom electrical selections available

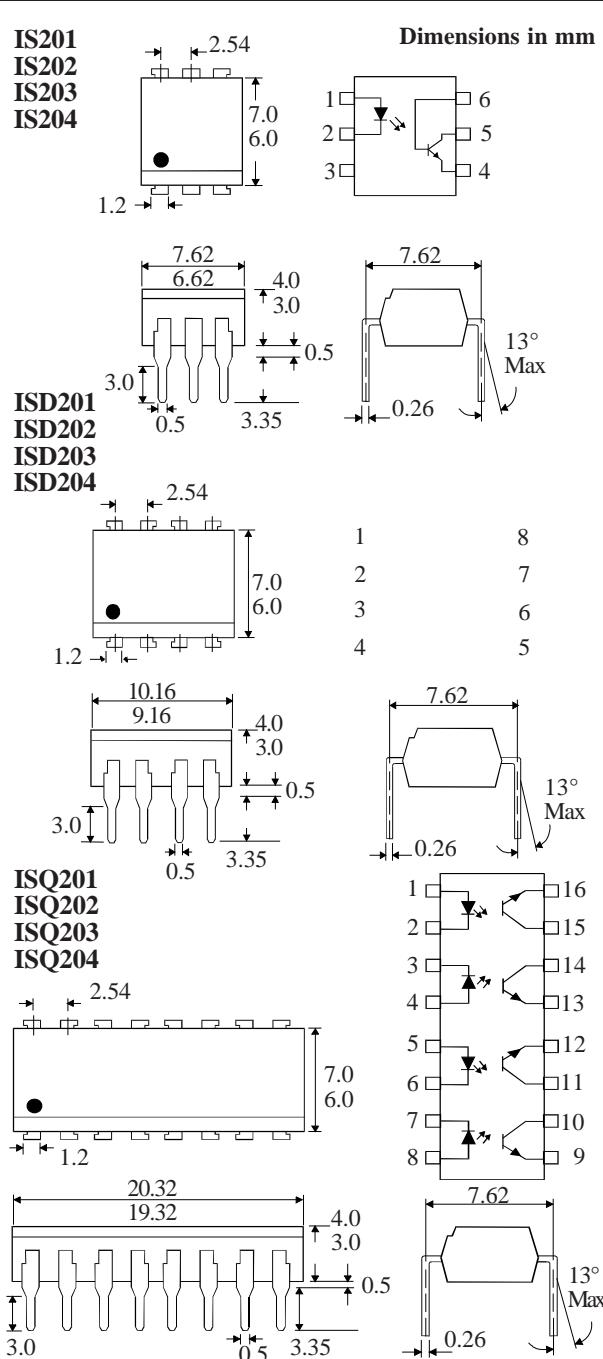
APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Signal transmission between systems of different potentials and impedances

OPTION SM SURFACE MOUNT



OPTION G



ISOCOM COMPONENTS 2004 LTD

Unit 25B, Park View Road West,
Park View Industrial Estate, Brenda Road
Hartlepool, Cleveland, TS25 1UD
Tel: (01429) 863609 Fax: (01429) 863581

ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature	-40°C to +125°C
Operating Temperature	-25°C to +100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

Forward Current	50mA
Reverse Voltage	6V
Power Dissipation	70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO}	70V
Emitter-collector Voltage BV_{ECO}	6V
Collector Current	50mA
Power Dissipation	150mW

POWER DISSIPATION

Total Power Dissipation	170mW
(derate linearly 2.67mW/°C above 25°C)	

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ C$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.65	V	$I_F = 50mA$
	Reverse Current (I_R)			10	μA	$V_R = 4V$
Output	Collector-emitter Breakdown (BV_{CEO}) (Note 2)	70			V	$I_C = 1mA$
	Emitter-collector Breakdown (BV_{ECO}) Collector-emitter Dark Current (I_{CEO})	6		50	V nA	$I_E = 100\mu A$ $V_{CE} = 10V$
Coupled	Current Transfer Ratio (CTR) (Note 2) IS201, ISD201, ISQ201	75			%	$10mA I_F, 10V V_{CE}$
	IS201, ISD201, ISQ201	10			%	$1mA I_F, 10V V_{CE}$
	IS202, ISD202, ISQ202	125		250	%	$10mA I_F, 10V V_{CE}$
	IS202, ISD202, ISQ202	30			%	$1mA I_F, 10V V_{CE}$
	IS203, ISD203, ISQ203	225		450	%	$10mA I_F, 10V V_{CE}$
	IS203, ISD203, ISQ203	50			%	$1mA I_F, 10V V_{CE}$
	IS204, ISD204, ISQ204	200		400	%	$10mA I_F, 10V V_{CE}$
	IS204, ISD204, ISQ204	100			%	$1mA I_F, 10V V_{CE}$
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$		0.2	0.4	V	$10mA I_F, 2mA I_C$
	Input to Output Isolation Voltage V_{ISO}	5300			V_{RMS}	See note 1
		7500			V_{PK}	See note 1
	Input-output Isolation Resistance R_{ISO}	5×10^{10}			Ω	$V_{IO} = 500V$ (note 1)
	Output Turn on Time t_{ON}			3.0	μs	$I_F = 10mA$
	Output Turn off Time t_{OFF}			2.5	μs	$V_{CE} = 5V, R_L = 75\Omega$

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

